

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	22792	substrate and (semiconductor near2 (fab or fabricat\$5))	USPAT; EPO; JPO
2	BRS	L5	367	(detect\$ or determin\$5 or measur\$) near5 (foreign near2 particle)	USPAT; EPO; JPO
3	BRS	L6	11	1 and 5	USPAT; EPO; JPO
4	BRS	L10	313	(detect\$ or determin\$5) near5 (foreign near2 particle)	USPAT; EPO; JPO
5	BRS	L11	26538	(first and second) near4 process\$5	USPAT; EPO; JPO
6	BRS	L15	40194	transfer\$5 near5 (substrate or wafer)	USPAT; EPO; JPO
7	BRS	L19	1	5 and 11 and 15	USPAT; EPO; JPO
8	BRS	L23	46	10 and 15	USPAT; EPO; JPO